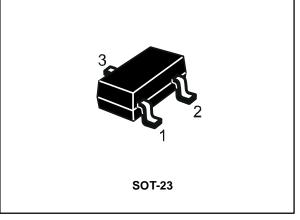


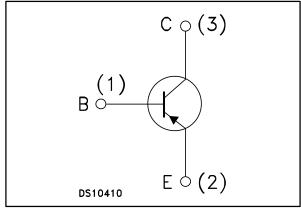
# 2STR2160

### Low voltage fast-switching PNP power transistor

Datasheet - production data



#### Figure 1: Internal schematic diagram



This is information on a product in full production.

#### **Features**

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

### Applications

- LED
- Battery charger
- Motor and relay driver
- Voltage regulation

### Description

The device in a PNP transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

The complementary NPN is the 2STR1160.

#### Table 1: Device summary

Table 1. Device Summary				
Order code	Marking	Package	Packing	
2STR2160	2160	SOT-23	Tape and reel	

1/8

### Contents

1	Electric	al ratings	. 3
2	Electric	al characteristics	.4
3	Packag	e mechanical data	. 5
	3.1	SOT-23 mechanical data	.5
4	Revisio	n history	.7



### 1 Electrical ratings

 Table 2: Absolute maximum rating

Symbol	Parameter	Value	Unit
Vсво	Collector-base voltage ( $I_E = 0$ )	-60	V
V <sub>CEO</sub>	Collector-emitter voltage $(I_B = 0)$	-60	V
VEBO	Emitter-base voltage (Ic = 0)	-5	V
lc	Collector current	-1	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	-2	А
Ptot	Total dissipation at T <sub>amb</sub> = 25°C	0.5	W
Tstg	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

#### Table 3: Thermal data

Symbol	Parameter	Value	Unit
Rthj-amb <sup>(1)</sup>	Thermal resistance junction-amb max	250	°C/W

#### Notes:

<sup>(1)</sup>Device mounted on PCB area of 1 cm<sup>2</sup>



### 2 Electrical characteristics

(T<sub>case</sub> = 25°C unless otherwise specified)

	Table 4:	Electrical	characteristics
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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Ісво	Collector cut-off current (I <sub>E</sub> =0)	V <sub>CB</sub> = -60 V			-0.1	μA
Іево	Emitter cut-off current (I <sub>C</sub> =0)	V <sub>EB</sub> = -5 V			-0.1	μA
V(br)cbo	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ic = -100 μA	-60			V
V(br)ceo <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -10 mA	-60			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (Ic = 0)	I <sub>E</sub> = -100 μA	-5			V
V <sub>CE(sat)</sub>	Collector-emitter	$I_{C} = -0.5 \text{ A} I_{B} = -50 \text{ mA}$			260	mV
VCE(sat)	saturation voltage	$I_{C} = -1 \text{ A } I_{B} = -100 \text{ mA}$			480	mV
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	Ic = -1 A I <sub>B</sub> = -100 mA			1.3	V
		$I_{C} = -0.5 \text{ A V}_{CE} = -2 \text{V}$	180		560	
h <sub>FE</sub>	DC current gain	$I_{C} = -1 \text{ A } V_{CE} = -2 \text{ V}$	45			
		$I_{C} = -2 A V_{CE} = -2 V$		30		
	Resistive load					
t <sub>on</sub>	Turn-on time	$I_{C} = -1.5 \text{ A V}_{CC} = -10 \text{ V}$		220		ns
t <sub>off</sub>	Turn-off time	$I_{B1} = -I_{B2} = -150 \text{ mA}$ $V_{BB(off)} = 5 \text{ V}$		500		ns

#### Notes:

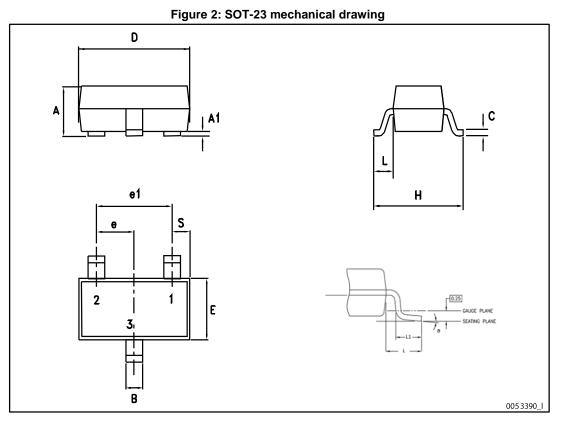
 $^{(1)}\text{Pulse test:}$  pulse duration = 300 µs, duty cycle  $\leq$  1.5 %



### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

### 3.1 SOT-23 mechanical data

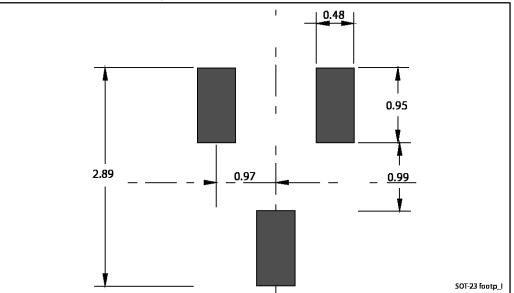




#### Package mechanical data

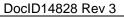
Table 5: SOT-23 mechanical data					
<b>D</b>	mm				
Dim.	Min.	Тур.	Max.		
A	0.89		1.40		
A1	0		0.10		
В	0.30		0.51		
С	0.085		0.18		
D	2.75		3.04		
е	0.85		1.05		
e1	1.70		2.10		
E	1.20		1.75		
Н	2.10		3.00		
L		0.60			
S	0.35		0.65		
L1	0.25		0.55		
а	0°		8°		







Dimensions are in mm.





## 4 Revision history

Table 6: Document revision history

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Date	Revision	Changes
18-Jun-2008	1	Initial release
08-May-2014	2	Updated Section 3: "Package mechanical data".
13-Mar-2015	3	Updated marking in Table 1: "Device summary"



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